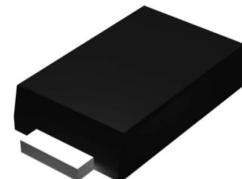


Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- For surface mount applications
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- Low profile package
- Built-in strain relief, ideal for automated placement
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU



SMAF



RoHS
COMPLIANT

Mechanical Data

- Case: SMAF molded plastic body
- Terminals: Solder plated, solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end

Maximum Ratings

(Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%.)

Parameter	Symbols	GSS 32S	GSS 33S	GSS 34S	GSS 36S	GSS 310S	GSS 315S	GSS 320S	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	60	100	150	200	V
Maximum RMS Voltage	V_{RMS}	14	21	28	42	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	60	100	150	200	V
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Length (See Figure) ¹	$I_{(AV)}$	3.0						A	
Peak Forward Surge Current 8.3ms Single Half Sine-wave Superimposed On Rated Load (JEDEC Method)	I_{FSM}	80.0						A	
Typical Thermal Resistance	$R_{\theta JA}$	50.0						°C/W	
Operating Junction Temperature Range	T_J	-55 to +150						°C	
Storage Temperature Range	T_{STG}	-55 to +150						°C	

Electrical Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%.)

Parameter	Symbols	Conditions	GSS 32S	GSS 33S	GSS 34S	GSS 36S	GSS 310S	GSS 315S	GSS 320S	Units
Maximum Instantaneous Forward Voltage ¹	V_F	$I_F=3.0A$	0.55		0.70	0.85	0.90	0.95	V	
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage ¹	I_R	$T_A=25^\circ C$	100			20			μA	
		$T_A=100^\circ C$	5			-			mA	
		$T_A=125^\circ C$	-			3				
Typical Junction Capacitance ²	C_J	-	160			100			pF	

Notes:

1. Pulse test: 300μs pulse width, 1% duty cycle
2. Measured at 1MHz and reverse voltage of 4.0V

GSS32S thru GSS320S

Surface Mount Schottky Barrier Rectifiers
 Reverse Voltage 20V to 200V Forward Current 3A

Ratings and Characteristics Curves

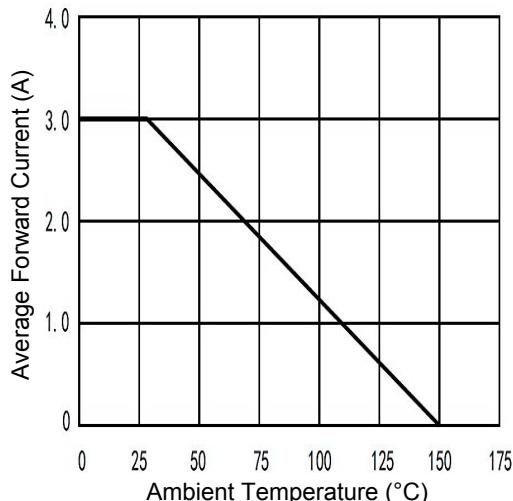


Figure 1. Forward Current Derating Curve

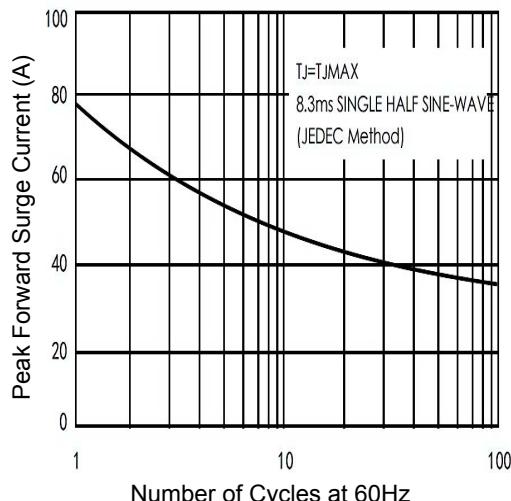


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

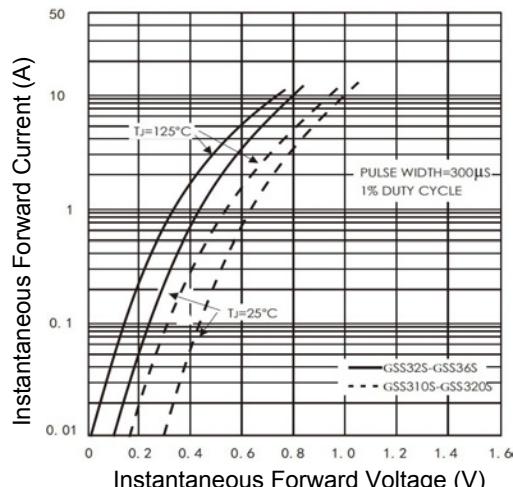


Figure 3. Typical Instantaneous Forward Characteristics

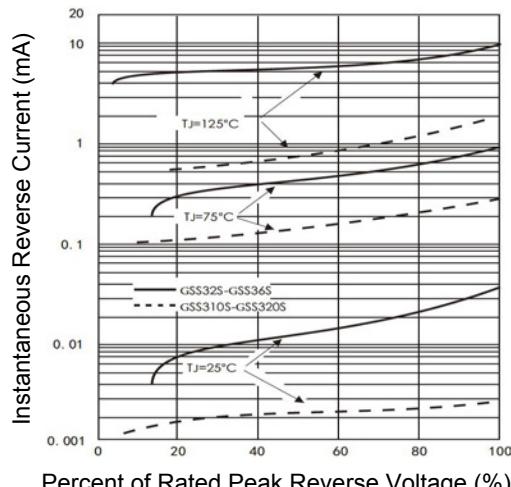


Figure 4. Typical Reverse Characteristics

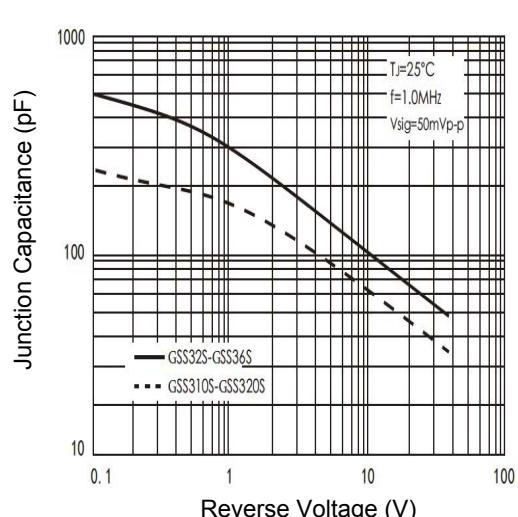
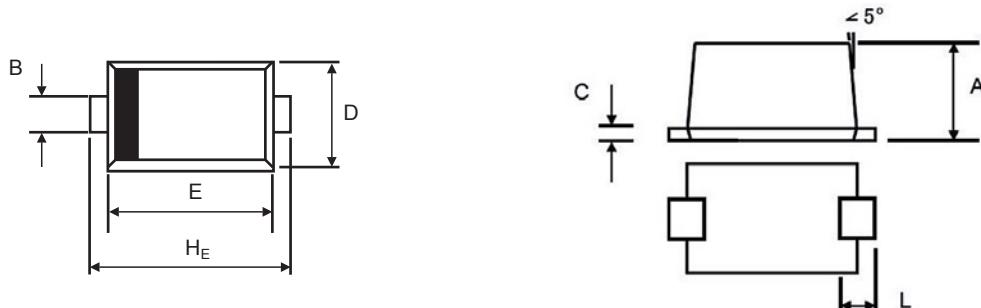


Figure 5. Typical Junction Capacitance

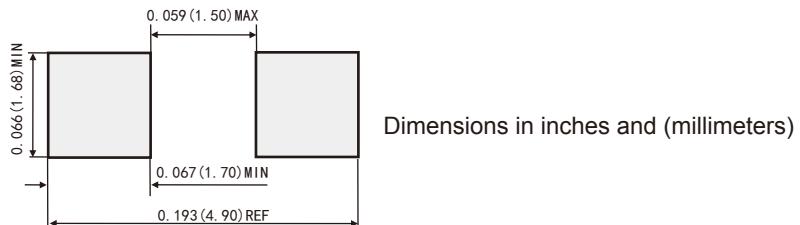
Surface Mount Schottky Barrier Rectifiers
 Reverse Voltage 20V to 200V Forward Current 3A

Package Outline Dimensions (SMAF)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.90	1.50	0.035	0.059
B	1.30	1.60	0.051	0.063
C	0.10	0.30	0.004	0.012
D	2.40	2.80	0.094	0.110
E	3.25	3.70	0.128	0.146
HE	4.35	4.90	0.172	0.193
L	0.60	1.20	0.028	0.047

Recommended Pad Layout



Order Information

Device	Package	Marking Code	Carrier	Quantity
GSS32S	SMAF	SS32S	Tape & Reel	3,000 Pcs / Reel
GSS33S	SMAF	SS33S	Tape & Reel	3,000 Pcs / Reel
GSS34S	SMAF	SS34S	Tape & Reel	3,000 Pcs / Reel
GSS36S	SMAF	SS36S	Tape & Reel	3,000 Pcs / Reel
GSS310S	SMAF	SS310S	Tape & Reel	3,000 Pcs / Reel
GSS315S	SMAF	SS315S	Tape & Reel	3,000 Pcs / Reel
GSS320S	SMAF	SS320S	Tape & Reel	3,000 Pcs / Reel

For more information, please contact us at: inquiry@goodarksemi.com